

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







MPQ2907A

PNP SILICON QUAD TRANSISTOR



www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR MPQ2907A type is comprised of four independent PNP silicon transistors mounted in a 14-pin DIP, designed for small signal, general purpose amplifier and switching applications.





MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Continuous Collector Current	I _C	600	mA
Power Dissipation (per transistor)	P_{D}	650	mW
Power Dissipation (total package)	P_{D}	2.0	W
Operating and Storage Junction Temperature	T _{.I} , T _{sta}	-65 to +150	°C

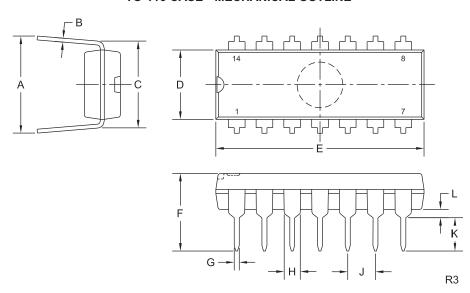
		0 0.9			
ELECTRICA	AL CHARACTERISTICS PER TRANSIS	STOR: (T _A =2	5°C)		
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
ICBO	V _{CB} =30V			50	nA
I _{EBO}	V _{EB} =3.0V			50	nA
BV _{CBO}	I _C =10μA	60			V
BVCEO	I _C =10mA	60			V
BVEBO	I _E =10μA	5.0			V
V _{CE} (SAT)	I _C =150mA, I _B =15mA			0.4	V
VCE(SAT)	I _C =300mA, I _B =30mA			1.6	V
V _{BE} (SAT)	I _C =150mA, I _B =15mA			1.3	V
V _{BE} (SAT)	I _C =300mA, I _B =30mA			2.6	V
h _{FE} ` ´	V _{CE} =10V, I _C =10mA	75			
hFE	V _{CE} =10V, I _C =150mA	100			
hFE	V_{CE} =10V, I_{C} =300mA	50			
f _T	V_{CE} =20V, I_{C} =50mA, f=100MHz	200			MHz
C _{ob}	V_{CB} =10V, I_E =0, f=1.0MHz		6.0	8.0	pF
C _{ib}	V_{BE} =2.0V, I_{C} =0, f=1.0MHz		20	30	pF
ton	V_{CC} =30V, I_{C} =150mA, I_{B1} =15mA		30		ns
t _{off}	V _{CC} =6.0V, I _C =150mA, I _{B1} =I _{B2} =15r	mA	150		ns

MPQ2907A

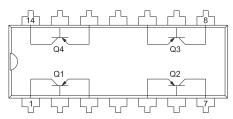
PNP SILICON QUAD TRANSISTOR



TO-116 CASE - MECHANICAL OUTLINE



PIN CONFIGURATION



LEAD CODE:

- 1) Collector Q1 2) Base Q1 3) Emitter Q1 4) No Connection
- 8) Collector Q3 9) Base Q3 10) Emitter Q3
- 4) No Connection 5) Emitter Q2 12) Emitter Q4
- 6) Base Q2 13) Base Q4 7) Collector Q2 14) Collector Q4

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0.310	0.390	7.9	9.9			
В	0.008	0.014	0.2	0.4			
С	0.310		7.9				
D	0.240	0.260	6.1	6.6			
Е	0.740	0.760	18.8	19.3			
F	-	0.300	-	7.6			
G	0.014	0.022	0.4	0.6			
Н	0.050		1.3				
J	0.100		2.5				
K	0.125	0.150	3.2	3.8			
Ĺ	0.015	-	0.4	-			

TO-116 (REV: R3)

MARKING: FULL PART NUMBER

R1 (30-January 2012)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA

Main Tel: (631) 435-1110 Main Fax: (631) 435-1824

Support Team Fax: (631) 435-3388

www.centralsemi.com

Worldwide Field Representatives: www.centralsemi.com/wwreps

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